



Solid State Devices, Inc.

14701 Firestone Blvd * La Mirada, CA 90638
 Phone: (562) 404-4474 * Fax: (562) 404-1773
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**SDR2HF1.8 and SMS
SDR2HF2.0 and SMS**

**2 AMPS
1800 - 2000 VOLTS
35 nsec
HYPER FAST RECOVERY
RECTIFIER**

Designer's Data Sheet

Part Number/Ordering Information ^{1/}
SDR2HF

L **Screening ^{2/}**
 ___ = Not Screened
 TX = TX Level
 TXV = TXV Level
 S = S Level

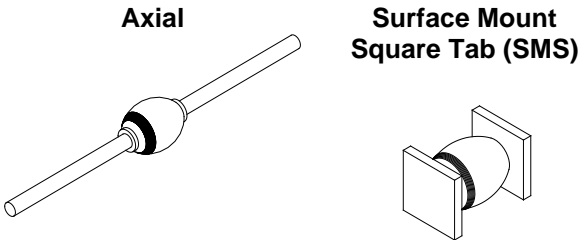
Package Type
 ___ = Axial
 SMS = Surface Mount
 Square Tab

Family/Voltage
 1.8 = 1800 V
 2.0 = 2000 V

- FEATURES:**
- Hyper Fast Recovery: 35 nsec maximum
 - PIV to 2400 Volts
 - Low Reverse Leakage Current
 - Hermetically Sealed
 - Low Thermal Resistance
 - Low trr Change at High Temperature (typical: trr = 55 ns @ 100°C)
 - TX, TXV, and Space Level Screening Available.^{2/} Contact Factory.
 - Fast Recovery Versions Available. Contact Factory.
 - Single Junction Construction
 - Replaces 1N6512 and 1N6513 in many applications.

MAXIMUM RATINGS		Symbol	Value	Unit
Reverse Voltage	SDR2HF1.8 & SMS SDR2HF2.0 & SMS	V_{RRM} V_{RWM} V_R	1800 2000	V
Average Rectified Forward Current (Resistive Load, 60 Hz, Sine Wave, $T_A = 25^\circ\text{C}$, $L = 0''$)		I_o	2	A
Peak Surge Current (1 ms Pulse, Square Wave, Allow Junction to Reach Equilibrium between Pulses, $T_A = 25^\circ\text{C}$, $L = .125''$)		I_{FSM}	16	A
Temperature Range	Operating Storage	T_{OP} T_{stg}	-65 to +175 -65 to +200	°C
Maximum Thermal Resistance Junction to Lead, $L = 0.125''$ (Axial Lead) Junction to End Tab (Surface Mount)		$R_{\theta JL}$ $R_{\theta JE}$	11 7	°C/W

^{1/} For Ordering Information, Price, Operating Curves, and Availability- Contact Factory.
^{2/} Screening Based on MIL-PRF-19500. Screening Flow Available on Request.





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ELECTRICAL CHARACTERISTICS		Symbol	Min	Max	Unit
Breakdown Voltage ($I_R = 50 \mu A$, $T_A = 25^\circ C$, Pulse)	SDR2HF1.8 & SMS SDR2HF2.0 & SMS	BV_R	1800 2000	— —	V
Instantaneous Forward Voltage Drop ($T_A = 25^\circ C$, Pulse)	$I_{F1} = 1 A$	V_{F1}	—	8.0	V
	$I_{F2} = 2 A$	V_{F2}	—	11.0	V
Instantaneous Forward Voltage Drop ($T_A = -55^\circ C$, Pulse)	$I_{F3} = 1 A$	V_{F3}	—	8.0	V
	$I_{F4} = 2 A$	V_{F4}	—	11.0	V
Reverse Leakage Current ($V_R = 85\%$ rated V_R , Pulse)	$T_A = 25^\circ C$	I_{R1}	—	10	μA
	$T_A = 100^\circ C$	I_{R2}	—	250	μA
Junction Capacitance ($V_R = 50 V_{DC}$, $T_A = 25^\circ C$, $f = 1 MHz$)		C_J	—	20	pF
Reverse Recovery Time ($I_F = 500 mA$, $I_R = 1 A$, $I_{RR} = 250 mA$, $T_A = 25^\circ C$)		t_{rr}	—	35	ns

Case Outline: (Axial)

DIM	MIN	MAX
A	—	0.170"
B	0.210"	0.250"
C	0.045"	0.051"
D	1.000"	—

Case Outline: (SMS)

DIM	MIN	MAX
A	0.173"	0.205"
B	0.255"	0.280"
C	0.020"	0.030"
D	0.002"	—

NOTES:
 Consult manufacturing for operating curves.